

Data Sheet N1703, Rev. B

MBR30100DJF

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MBR30100DJF SCHOTTKY RECTIFIER



Circuit Diagram



Features

- Designed as Bypass Diodes for Solar Panels
- for High Thermal Reliability
- High Forward Surge Capability
- Ultra Low Forward Voltage Drop
- Excellent High Temperature Stability
- Terminals finish: 100% Pure Tin
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
 Bayerree better i protoction
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	100	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=90°C, rectangular wave form	30	А
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse, T_c = 25 °C 200		А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 15 A, Pulse, T _J = 25 °C @ 30 A, Pulse, T _J = 25 °C	0.75 0.86	0.82 0.96	V
	V _{F2}	@ 15 A, Pulse, TJ = 125 °C @ 30 A, Pulse, TJ = 125 °C	0.63 0.74	0.66 0.78	V
Reverse Current*	I _{R1}	$@V_R = rated V_R$ T _c = 25 °C	12	100	uA
Reverse Current*	I _{R2}	@V _R = rated V _R T _c = 125 °C	6	40	mA
Junction Capacitance	Ст	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	506	600	pF

* Pulse width < 300 μ s, duty cycle < 2%

- China Germany Korea Singapore United States •
- http://www.smc-diodes.com sales@ smc-diodes.com •



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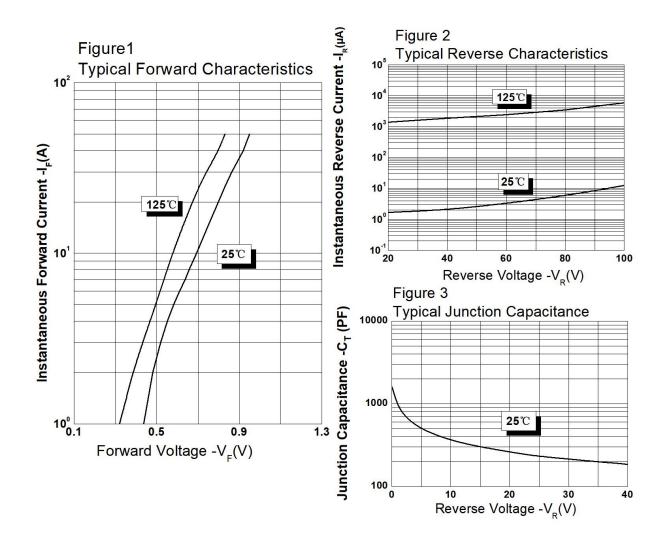
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Thermal-Mechanical Specifications:

Characteristics	Symbol Condition		Specification	Units
Junction Temperature	TJ	-	-55 to +175	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Ambient	$R_{ heta JA}$	DC operation	2.5	°C/W
Approximate Weight	wt	-	0.095	g

Ratings and Characteristics Curves



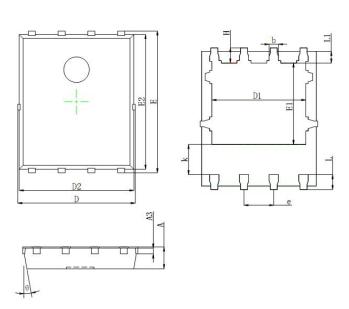


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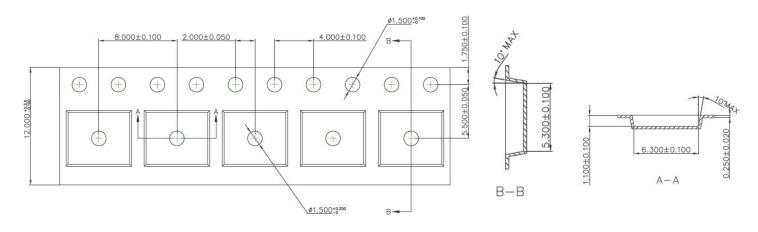
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Mechanical Dimensions PDFNWB5×6-8L



SYMBOL	Millimeters		Inches	
STMBOL	Min.	Max.	Min.	Max.
A	0.900	1.000	0.035	0.039
A3	0.254 REF.		0.010REF.	
D	4.944	5.096	0.195	0.201
E	5.974	6.126	0.235	0.241
D1	3.910	4.110	0.154	0.162
E1	3.375	3.575	0.133	0.141
D2	4.824	4.976	0.190	0.196
E2	5.674	5.826	0.223	0.229
k	1.190	1.390	0.047	0.055
b	0.350	0.450	0.014	0.018
е	1.270 TYP.		0.050 TYP.	
L	0.559	0.711	0.022	0.028
L1	0.424	0.576	0.017	0.023
Н	0.574	0.726	0.023	0.029
Θ	10°	12°	10°	12°

Carrier Tape Specification PDFNWB5×6-8L(mm)

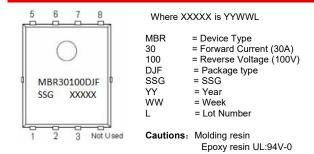


Ordering Information

Device	Package	Shipping	
MBR30100DJF	PDFNWB5×6-8L (Pb-Free)	3000 pcs / reel	
MBR30100DJFTR	PDFNWB5×6-8L (Pb-Free)	3000 pcs / reel	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



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